## NSN 5961-01-197-2006

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View Online at https://aerobasegroup.com/nsn/5961-01-197-2006 **Inclosure Material:** Metal **Overall Length:** 1.118 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 emitter to base voltage, static, collector open and 60.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 1.00 milliamperes zero-gate-voltage source current preset and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator: Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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